## NSN 5961-01-272-6273

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View Online at https://aerobasegroup.com/nsn/5961-01-272-6273

View Online at https://aerobasegroup.com/nsn/5961-01-2/2-62/3
Inclosure Material:
Metal
Overall Length:
1.525 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-63
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Threaded stud
Overall Width Across Flats:
0.875 inches
Thread Size:
0.312 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 collector to base voltage/static/emitter open and 300.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage,
static, collector open
Current Rating Per Characteristic:
20.00 amperes source cutoff current
Power Rating Per Characteristic:
150.0 watts small-signal input power, common-collector preset
Transfer Ratio:
12.0 static forward current transfer ratio, common-emitter and 60.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Special Features:
Junction pattern arrangement: npn
Precious Material And Location:
Terminal surface option gold
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Thread Series Designator:

813/0-mil-c-10500//12 government enecification

**Terminal Type And Quantity:** 

3 tab, solder lug

Specification Data:

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N/a

**Unit Of Measure:** 

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Demilitarization:

No

Fiig:

A110a0